
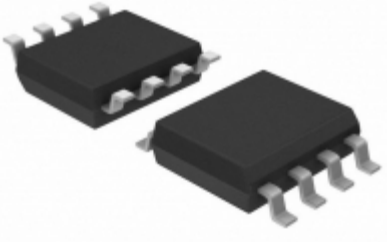


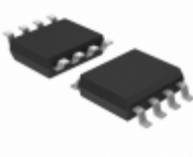


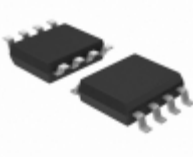
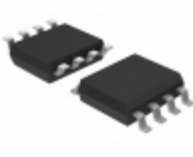

	<h2>SI4228DY-T1-GE3</h2>
	<p><b>Hersteller-Teilenummer:</b> SI4228DY-T1-GE3</p> <p><b>Hersteller / Marke:</b> Electro-Films (EFI) / Vishay</p> <p><b>Teil der Beschreibung:</b> MOSFET 2N-CH 25V 8A 8-SOIC</p> <p><b>Datenblätter:</b>  <a href="#">SI4228DY-T1-GE3.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 801681 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	SI4228DY-T1-GE3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET 2N-CH 25V 8A 8-SOIC
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	801681 pcs Stock
detaillierte Beschreibung	Mosfet Array 2 N-Channel (Dual) 25V 8A 3.1W Surface
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	3.1W
Verpackung / Gehäuse	8-SOIC (0.154", 3.90mm Width)
Supplier Device-Gehäuse	8-SO
Typ FET	2 N-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	25V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	8A
Rds On (Max) @ Id, Vgs	18 mOhm @ 7A, 10V
VGS (th) (Max) @ Id	1.4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	25nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	790pF @ 12.5V
Verpackung	Tape & Reel (TR)
Basisteilenummer	SI4228
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SI4228DY-T1-GE3TR

SI4228DY-T1-GE3 ist neu im Original, Suche SI4228DY-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI4228DY-T1-GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI4228DY-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p><b>SI4228DY-T1-E3</b> Electro-Films (EFI) / Vishay MOSFET 2N-CH 25V 8A 8SO</p>	 <p><b>Si4228DY</b> VISHAY SI4228DY VISHAY</p>	 <p><b>SI4230DY-T1-GE3</b> Vishay / Siliconix MOSFET 2N-CH 30V 8A 8SOIC</p>	 <p><b>SI4232DY.</b> FAI SI4232DY. FAI</p>
 <p><b>SI4276DY-T1-E3</b> Electro-Films (EFI) / Vishay MOSFET 2N-CH 30V 8A 8SO</p>	 <p><b>SI4226DY-T1-GE3</b> Vishay / Siliconix MOSFET 2N-CH 25V 8A 8-SOIC</p>	 <p><b>SI4226DY-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET 2N-CH 25V 8A 8-SOIC</p>	 <p><b>SI4230DY-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET 2N-CH 30V 8A 8SOIC</p>

### heiße Teile

Mehr

SI4209-A-GMR	SI4210-C-GMR	SI4210-D-GMR	SI4210-GM	SI4210DY-T1-E3
SI4210DY-T1-GE3	SI4210DY-T1-GE3	SI4210GM	SI4214DDY	SI4214DDY-T1-E3
SI4214DDY-T1-E3	SI4214DDY-T1-GE3	SI4214DDY-T1-GE3	SI4214DY-T1-E3	SI4214DY-T1-GE3
SI4214DY-T1-GE3	SI4220-GM	SI4226DY	SI4226DY-T1-E3	SI4226DY-T1-E3
SI4226DY-T1-GE3	SI4226DY-T1-GE3	SI4228DY	SI4228DY-T1-E3	SI4228DY-T1-E3
SI4228DY-T1-GE3	SI4232DY.	SI4276DY-T1-E3	SI4276DY-T1-E3	SI4282DVP
SI4286DY	SI4286DY-T1-GE3	SI4286DY-T1-GE3	SI4288DY	SI4288DY-T1-GE3
SI4288DY-T1-GE3	SI4300-BM	SI4300-E-BM	SI4300DY-T1-E3	SI4308DY-T1
SI4308DY-T1-E3	SI4311-B21-GMR	SI4320-J1-FTR	SI4320DY	SI4320DY-T1-E3
SI4320DY-T1-E3	SI4322-A0-FT	SI4322-A0-FTR	SI4322DY-T1-E3	SI4322DY-T1-E3

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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